

HMC427ALP3E

02 1016

GaAs MMIC POSITIVE CONTROL TRANSFER SWITCH, DC* - 8GHz

Typical Applications

The HMC427ALP3E is ideal for:

- Test Instrumentation
- Fiber Optics & Broadband Telecom
- Basestation Infrastructure
- Microwave Radio & VSAT
- Military Radios, Radar, & ECM

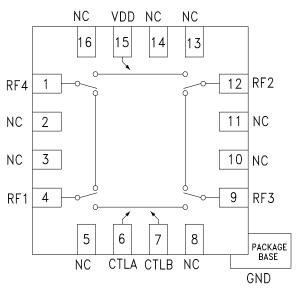
Features

High Isolation: 40 ~ 45 dB thru 6 GHz Low Insertion Loss: 1.5 dB at 6 GHz

Non-Reflective Design

3x3mm SMT Package

Functional Diagram



General Description

The HMC427ALP3E is a low loss broadband positive control transfer switch in leadless surface mount package. Covering DC to 8 GHz, this switch offers high isolation and low insertion loss. The switch operates using a positive control voltage of 0/+5V and requires a fixed bias of +5V at < 20 μ A.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, VDD = 5V, With 0/+5V Control, 50 Ohm System

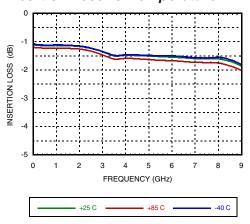
Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 6.0 GHz DC - 8.0 GHz		1.5 1.8	2 2.1	dB dB
Isolation	DC - 1.0 GHz DC - 2.0 GHz DC - 6.0 GHz DC - 8.0 GHz	45 40 36 35	50 45 43 43		dB dB dB dB
Return Loss	DC - 6.0 GHz DC - 8.0 GHz		18 18		dB dB
Input Power for 1 dB Compression	1.0 - 8.0 GHz	25	26		dBm dBm
Input Third Order Intercept (Two-Tone Input Power= +12 dBm Each Tone, 1 MHz Tone Separation)	1.0 - 8.0 GHz	40	43		dBm dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)	DC - 8.0 GHz		2 10		ns ns

^{*} Blocking capacitors are required at ports RF1, 2, 3, & 4. Their value will determine the lowest transmission frequency.

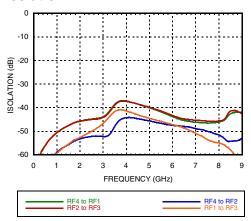


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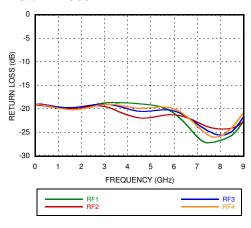
Insertion Loss vs. Temperature



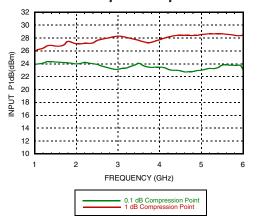
Isolation



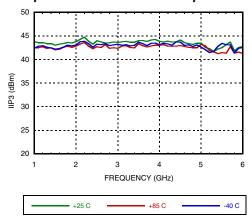
Return Loss



0.1 and 1 dB Input Compression Point



Input Third Order Intercept Point





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Absolute Maximum Ratings

Bias Voltage Range (VDD)	+7.0 VDC	
Control Voltage Range (CTRLA & CTRLB)	-0.5V to VDD +1.0 VDC	
Channel Temperature	150 °C	
Thermal Resistance	130 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
Maximum Input Power	+25.5 dBm (DC - 2 GHz)	
Maximum input Power	+27 dBm (2 GHz - 8 GHz)	
ESD Sensitivity (HBM)	Class 1A	
ESD Sensitivity (FICDM)	Class IV	



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Note:

DC blocking capacitors are required at ports RF1, 2, 3, & 4. Their value will determine the lowest transmission frequency.

Bias Voltage & Current

VDD Range = +5 VDC ± 10 %		
VDD IDD (Typ.) (VDC) (μA)		IDD (Max.) (μA)
+5	5	10

Control Voltages

	State	Bias Condition	
	Low	0 to +0.2 VDC at < 1 μA Typical	
High Vdd ± 0.2 VDC at < 1 μA Typical		Vdd ± 0.2 VDC at < 1 μA Typical	

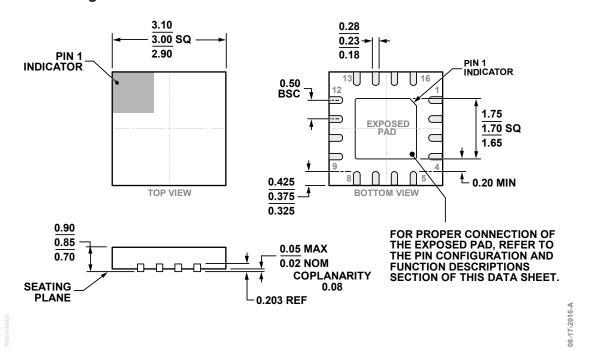
Truth Table

Control Input			Signal P	ath State	
А	В	RF4 to RF2	RF1 to RF3	RF4 to RF1	RF2 to RF3
Low	High	On	On	Off	Off
High	Low	Off	Off	On	On



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Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC427ALP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 ^[1]	H427A XXXX

^[1] Max peak reflow temperature of 260 °C

^{[2] 4-}Digit lot number XXXX



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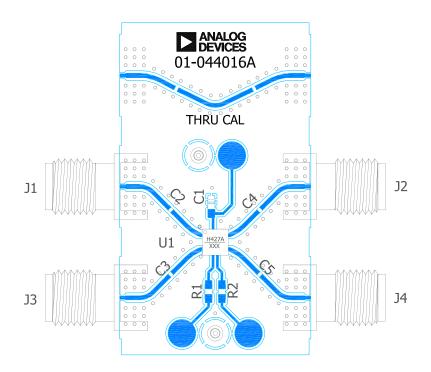
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 4, 9, 12	RF4, RF1, RF3, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required.	
2, 3, 5, 8, 10, 11, 13, 14, 16	NC	This pin should be connected to PCB RF ground to maximize isolation.	
	GND	Package bottom has exposed metal paddle that must be connected to PCB RF ground.	GND
6	CTRLA	See truth table and control voltage table.	0—R
7	CTRLB	See truth table and control voltage table.	c
15	VDD	Supply Voltage +5V ± 10%.	0



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Evaluation PCB



List of Materials for Evaluation PCB EV1HMC427ALP3E [1]

Item	Description	
J1 - J4	PCB Mount SMA RF Connector	
J5 - J8	DC Pin	
C1	1000 pF Capacitor, 0603 Pkg.	
C2 - C5	100 pF Capacitor, 0402 Pkg.	
R1 - R2	100 Ohm Resistor, 0603 Pkg.	
U1	HMC427ALP3E Transfer Switch	
PCB [2]	Evaluation PCB 01-044016A	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Analog Devices upon request.